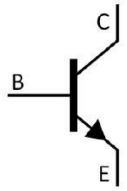
SOT-323 NPN Silicon NPN transistor in a SOT-323 Plastic Package.

- $V_{ce(sat)}$=0.3Vmax

Collectoe to emitter saturation voltage $V_{ce(sat)}$=0.3VmaxExcellent lineality of DC forward current gain,Supper mini package for easy mounting.

For hybrid IC,small type machine low frequency voltage amplify application.

Equivalent Circuit





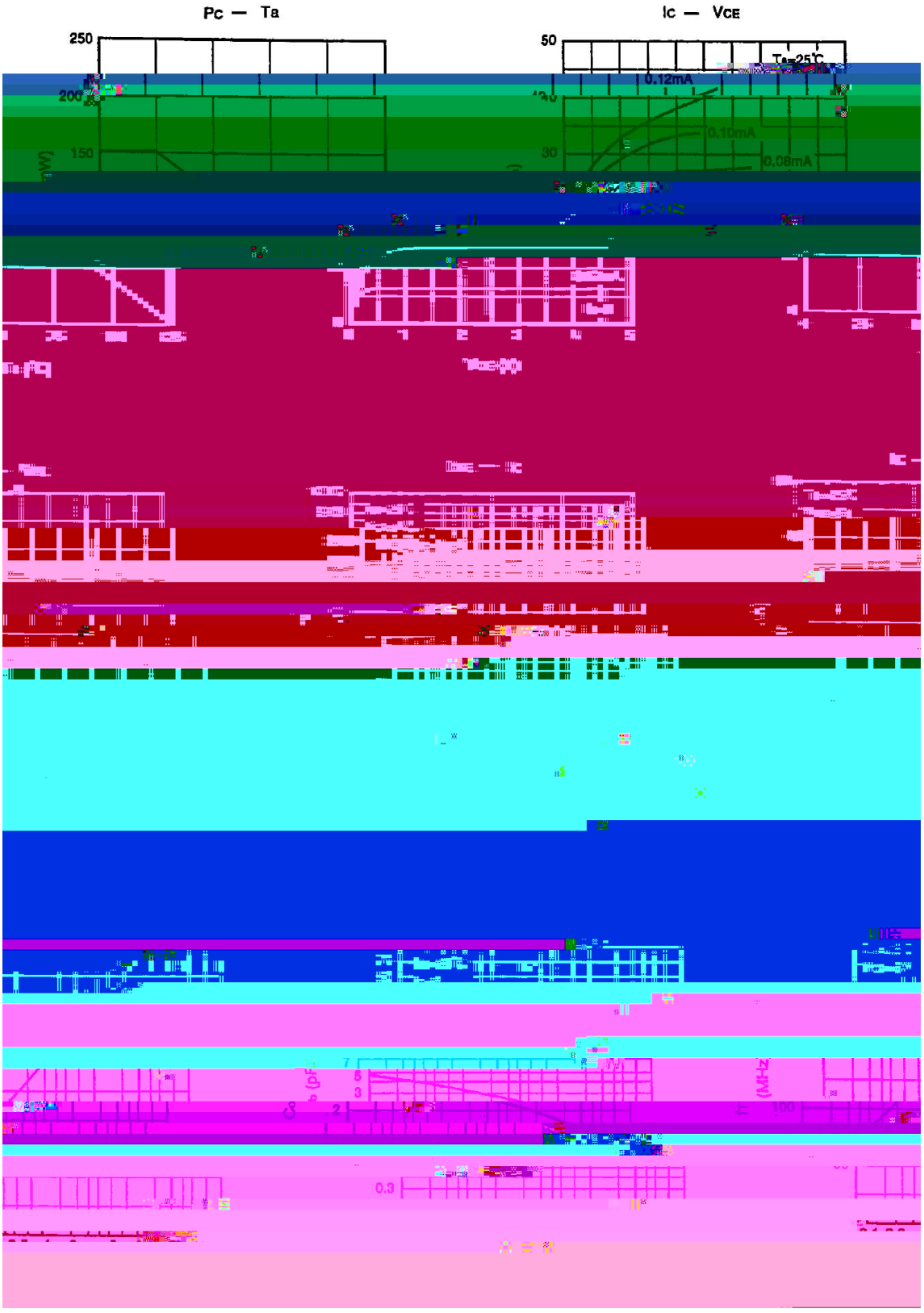
PIN1 Emitter PIN 2 Base PIN 3 Collector

Marking

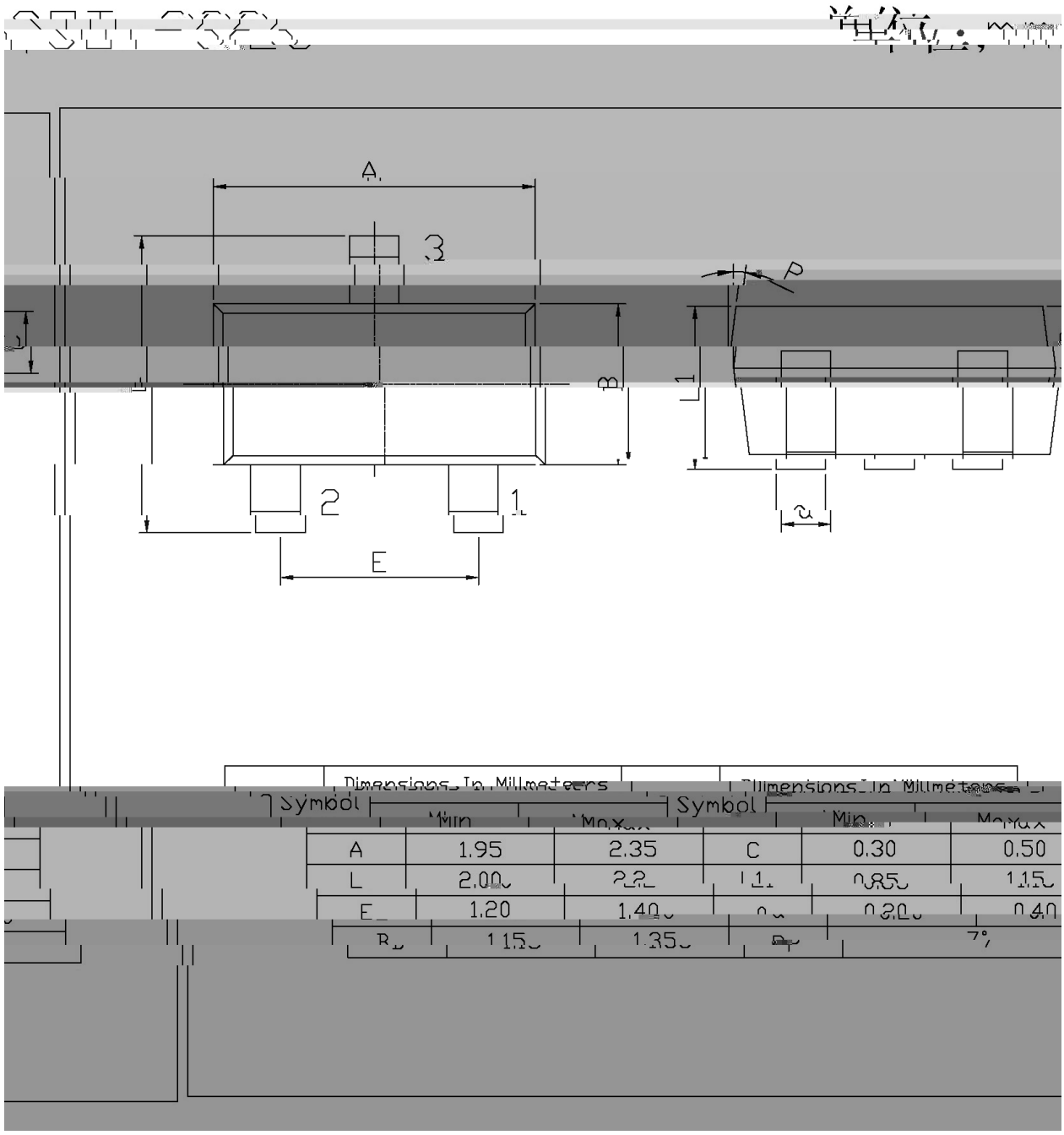
h_{FE} Classifications Symbol	Q	R	S	T
h_{FE} Range				

Parameter	Symbol		Rating	Unit
Collector to Base Voltage	V_{CBO}		50	V
Collector to Emitter Voltage	V_{CEO}		50	V
Emitter to Base Voltage	V_{EBO}		6	V
Collector Current - Continuous	I_C	2SC4155	0.1	A
		2SC4155A	0.2	
Collector Power Dissipation	P_C		150	mW

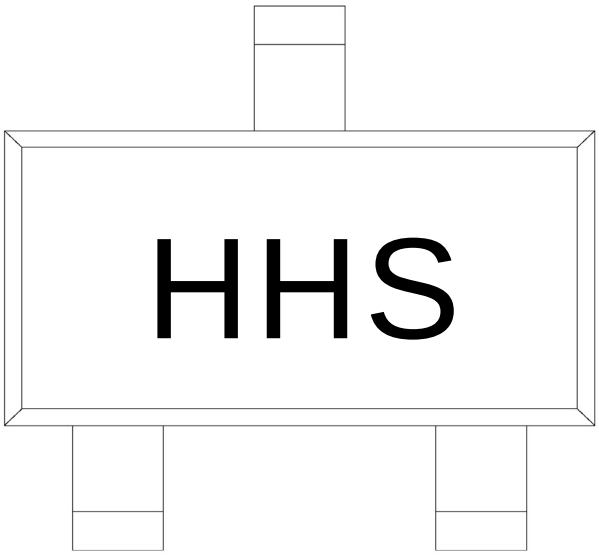
≠ ∃ ÃΆ´E ∀ ƒ / Electrical Characteristic Curve



ᵘ Ė Ồ Ļ ƒ / Package Dimensions



Ł. Ł Ω / Marking Instructions



H

H

S h_{FE}

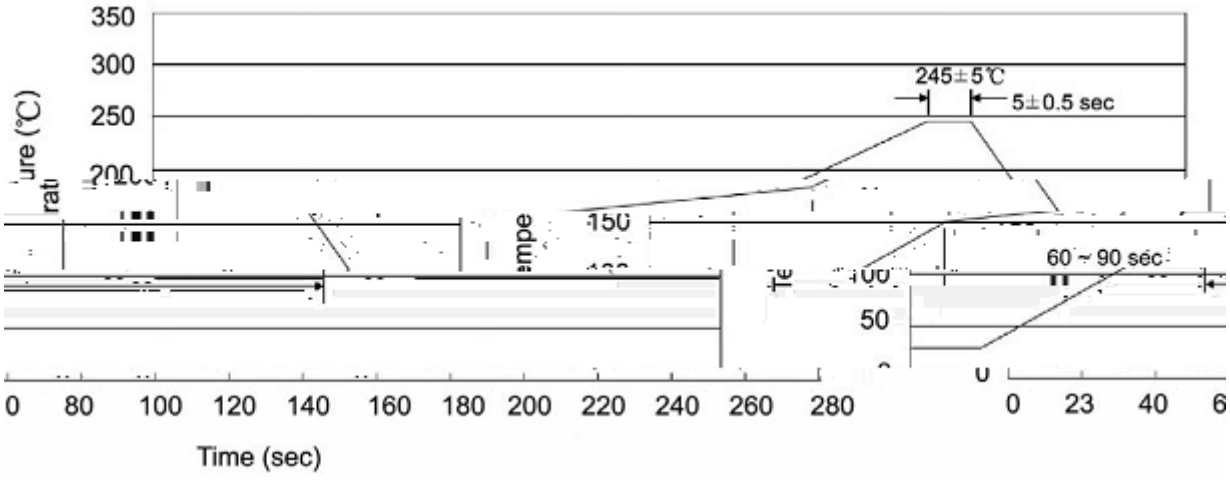
Note:

H: Company Code.

H: Product Type.

S: h_{FE} Classifications Symbol

ѭ ʃ ╕ ẘ ´E ⅵ ƒ (ᾠ ʓ) / Wh p shudwxuh Suriloh iru LU Uhio r z Vroghulq j+Se0luhh,



Note:

1	25	150	60	90sec;	1.Preheating:25~150 , Time:60~90sec.
2	245±5			5±0.5sec;	2.Peak Temp.:245±5 , Duration:5±0.5sec.
3		2	10	/sec.	3. Cooling Speed: 2~10 /sec.

ⅎ ü q ¯ `Y Ţ / Resistance to Soldering Heat Test Conditions

260±5	10±1 sec.	Temp.:260±5	Time:10±1 sec

ɒ Ŀ ≮ — / Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm^3)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-323	3,000	10	30,000	6	180,000	7 ×8	180×120×180	390×385×205

ä ѵ Ļ Ѽ / Notices